

Linear Single Cell Li-Ion Battery Charger IC

General Description

The HM8013 is a fully integrated low cost single-cell Li-Ion battery charger IC ideal for portable applications. The HM8013 is capable of being powered up from AC adapter. The HM8013 enters sleep mode when AC adapter is removed.

The HM8013 optimizes the charging task by using a control algorithm including preconditioning mode, fast charge mode and constant voltage mode. The charging task is terminated as the charge current drops below the preset threshold. The AC adapter charge current can be programmed up to 1A with an external resistor. The internal thermal feedback circuitry regulates the die temperature to optimize the charge rate for all ambient temperatures.

The HM8013 features 18V maximum rating voltages for AC adapter. The other features are under voltage protection, over voltage protection for AC adapter supply.

Ordering Information

HM8013	□	□
	Package Type	
	D : WDFN-10L 3x3 (W-Type)	
	Operating Temperature Range	
	G : Green (Halogen Free with Commercial Standard)	

Note :

Richtek Green products are :

- ▶ RoHS compliant and compatible with the current requirements of IPC/JEDEC J-ST D-020.
- ▶ Suitable for use in SnPb or Pb-free soldering processes.
- ▶ 100% matte tin (Sn) plating.

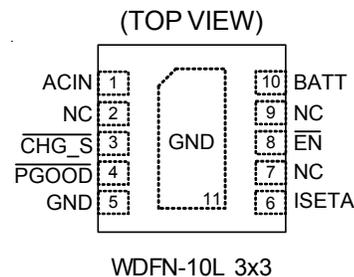
Features

- 18V Maximum Rating for AC Adapter
- Internal Integrate P-MOSFETs
- AC Adapter Power Good Status Indicator
- Charge Status Indicator
- Under Voltage Protection
- Over Voltage Protection
- Automatic Recharge Feature
- Small 10-Lead WDFN Package
- Thermal Feedback Optimizing Charge Rate
- RoHS Compliant and 100% Lead (Pb)-Free

Applications

- Digital Cameras
- Cellular Phones
- Personal Data Assistants (PDAs)
- MP3 Players
- Hand Held PCs

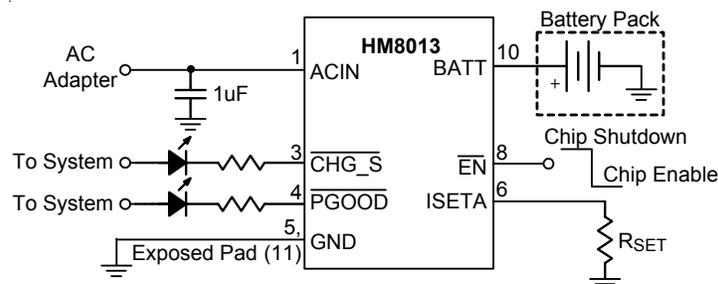
Pin Configurations



Marking Information

For marking information, contact our sales representative directly or through a Richtek distributor located in your area, otherwise visit our website for detail.

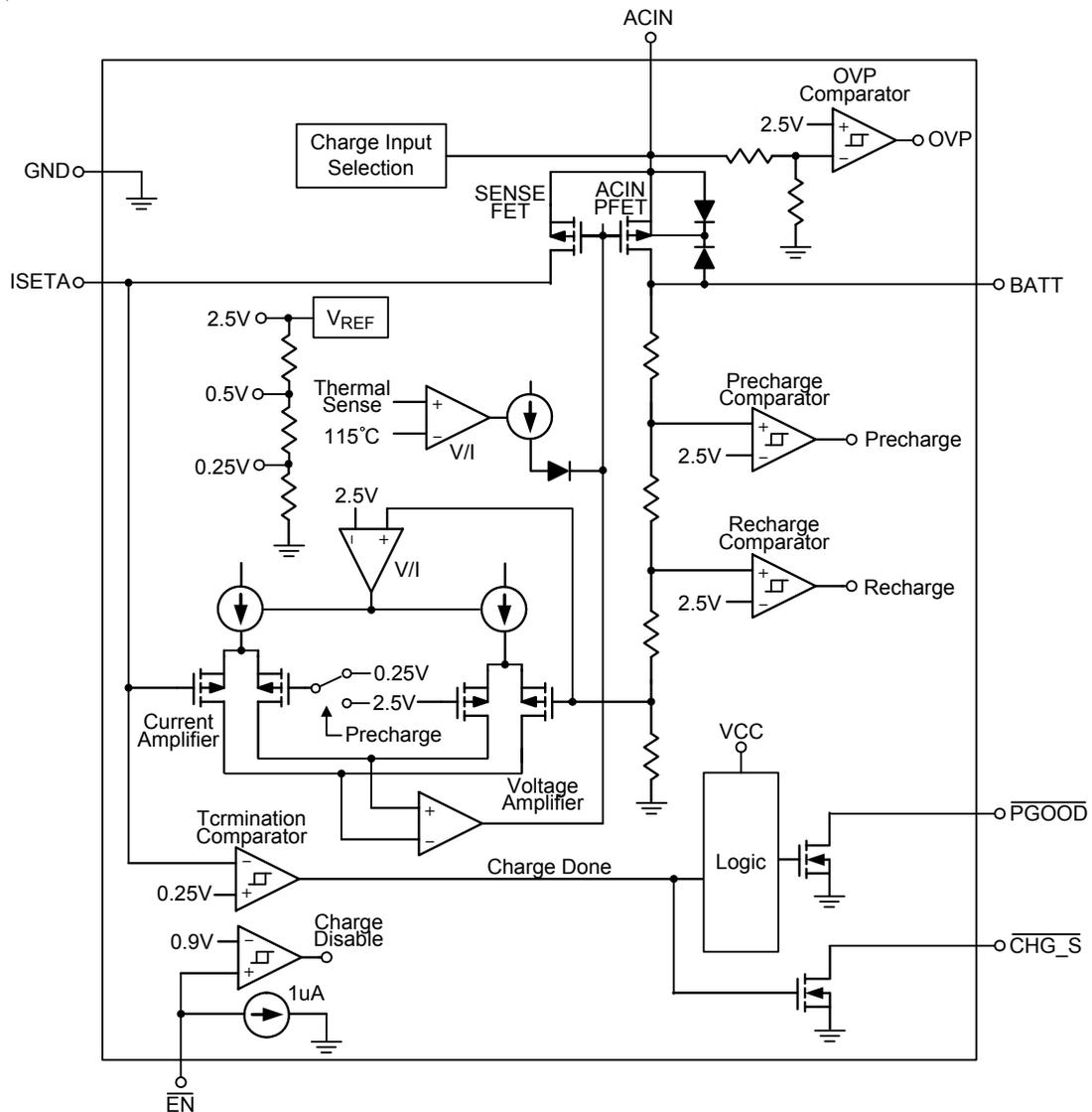
Typical Application Circuit



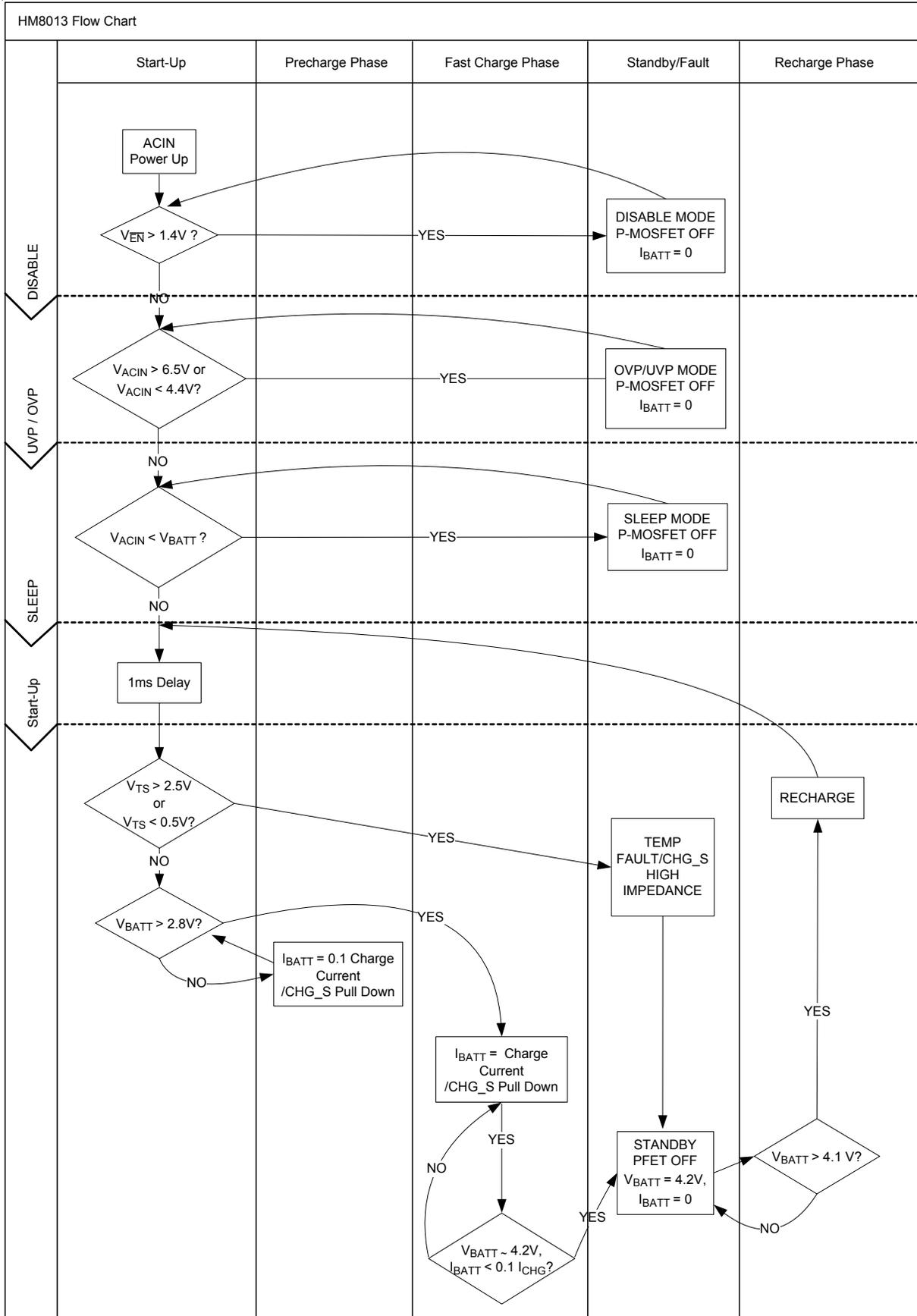
Functional Pin Description

Pin No.	Pin Name	Pin Function
1	ACIN	Wall Adaptor Charge Input Supply.
2, 7, 9	NC	No Internal Connection.
3	$\overline{\text{CHG_S}}$	Charge Status Indicator Output (open drain).
4	$\overline{\text{PGOOD}}$	Power Good Indicator Output (open drain).
5	GND	Ground.
6	ISETA	Wall Adaptor Supply Charge Current Set Point.
8	$\overline{\text{EN}}$	Charge Enable Input (active low).
10	BATT	Battery Charge Current Output.
Exposed Pad (11)	GND	Ground. The exposed pad must be soldered to a large PCB and connected to GND for maximum power dissipation.

Function Block Diagram



Table



Absolute Maximum Ratings (Note 1)

• AC Input Voltage	-----	-0.3V to 18V
• \overline{EN} Input Voltage	-----	-0.3V to 6V
• Output Current	-----	1.2A
• Power Dissipation, $P_D @ T_A = 25^\circ\text{C}$		
WDFN-10L 3x3	-----	0.926W
• Package Thermal Resistance (Note 4)		
WDFN-10L 3x3, θ_{JA}	-----	108°C/W
WDFN-10L 3x3, θ_{JC}	-----	8.2°C/W
• Lead Temperature (Soldering, 10 sec.)	-----	260°C
• Junction Temperature	-----	150°C
• Storage Temperature Range	-----	-65°C to 150°C
• ESD Susceptibility (Note 2)		
HBM (Human Body Mode)	-----	2kV
MM (Machine Mode)	-----	200V

Recommended Operating Conditions (Note 3)

• Junction Temperature Range	-----	-40°C to 125°C
• Ambient Temperature Range	-----	-40°C to 85°C

Electrical Characteristics

(ACIN = 5V, $T_A = 27^\circ\text{C}$, Unless Otherwise specification)

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Supply Input						
ACIN Input Voltage Range	V_{ACIN}		4.5	--	6	V
ACIN UVP Rising Threshold Voltage	V_{UV_HIGH}		--	4.4	4.5	V
ACIN UVP Hysteresis	V_{UV_LOW}		50	80	120	mV
ACIN Standby Current	I_{STBY}	$V_{BATT} = 4.5V$	--	300	500	μA
ACIN Shutdown Current	I_{SHDN}	$\overline{V_{EN}} = \text{HIGH}$	--	50	100	μA
ACIN UVP Current	I_{UVP}	$V_{ACIN} = 4V, V_{BATT} = 3V$	--	150	250	μA
BATT Sleep Leakage Current	I_{SLEEP}	$V_{ACIN} = 4V, V_{BATT} = 4.5V$	--	--	10	μA
Voltage Regulation						
BATT Regulation Voltage	V_{REG}	$I_{BATT} = 60\text{mA}$	4.158	4.2	4.242	V
Regulation Voltage Accuracy			-1	--	+1	%
ACIN MOSFET	$R_{DS(ON)_ACIN}$	$I_{BATT} = 500\text{mA}$	--	600	--	$\text{m}\Omega$
Current Regulation						
ISETA Set Voltage (Fast Charge Phase)	V_{ISETA}	$V_{BATT} = 3.5V$	2.45	2.5	2.55	V
Full Charge Setting Range	I_{CHG_AC}		100	--	1200	mA
AC Charge Current accuracy	I_{CHG_AC}	$V_{BATT} = 3.8V, R_{ISET} = 1.5\text{k}\Omega$	--	500	--	mA

To be continued

Parameter	Symbol	Test Conditions	Min	Typ	Max	Units
Precharge						
BATT Pre-Charge Rising Threshold	V _{PRECH}		2.6	2.8	3	V
BATT Pre-Charge Threshold Hysteresis	ΔV _{PRECH}		50	100	200	mV
Pre-Charge Current	I _{PCHG}	V _{BATT} = 2V	8	10	12	%
Recharge Threshold						
BATT Re-Charge Falling Threshold Hysteresis	ΔV _{RECH_L}	V _{REG} - V _{BATT}	60	100	150	mV
Charge Termination Detection						
Termination Current Ratio (default)	I _{TERM}	V _{BATT} = 4.2V	--	10	--	%
Logic Input/Output						
CHG_S Pull Down Voltage	V _{CHG_S}	TBD, I _{CHG_S} = 5mA	--	65	--	mV
PGOOD Pull Down Voltage	V _{PGOOD}	TBD, I _{PGOOD} = 5mA	--	220	--	mV
EN Threshold	Logic-High Voltage	V _{IH}	1.5	--	--	V
	Logic-Low Voltage	V _{IL}	--	--	0.4	V
EN Pin Input Current	I _{EN}	V _{EN} = 2V	--	--	2	μA
Protection						
Thermal Regulation			--	125	--	°C
OVP SET		Internal Default	--	6.5	--	V

Note 1. Stresses listed as the above "Absolute Maximum Ratings" may cause permanent damage to the device. These are for stress ratings. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may remain possibility to affect device reliability.

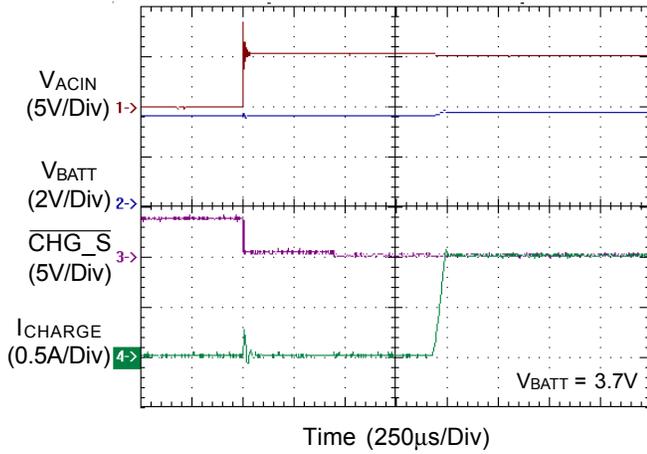
Note 2. Devices are ESD sensitive. Handling precaution recommended.

Note 3. The device is not guaranteed to function outside its operating conditions.

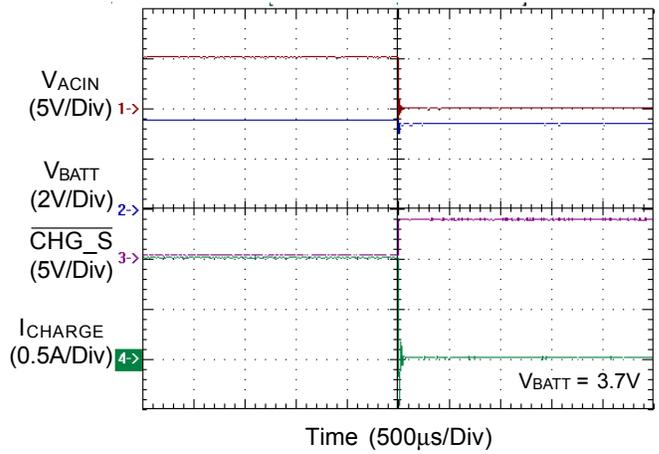
Note 4. θ_{JA} is measured in the natural convection at T_A = 25°C on a high effective thermal conductivity test board (4 layers, 1S) of JEDEC 51-7 thermal measurement standard. The case point of θ_{JC} is on the exposed pad for the WDFN package.

Typical Operating Characteristics

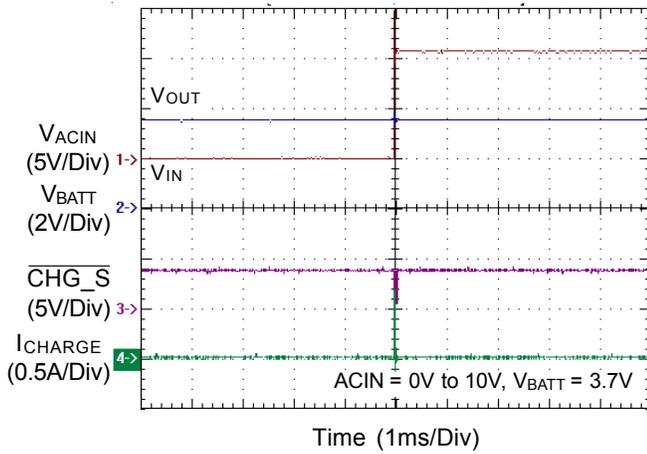
ACIN Power On



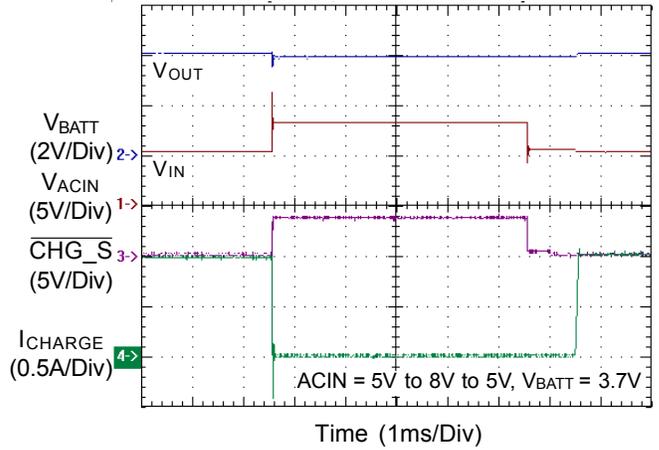
ACIN Power Off



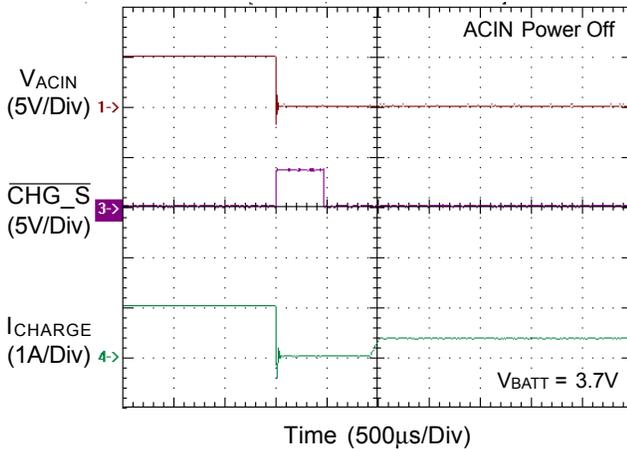
ACIN OVP



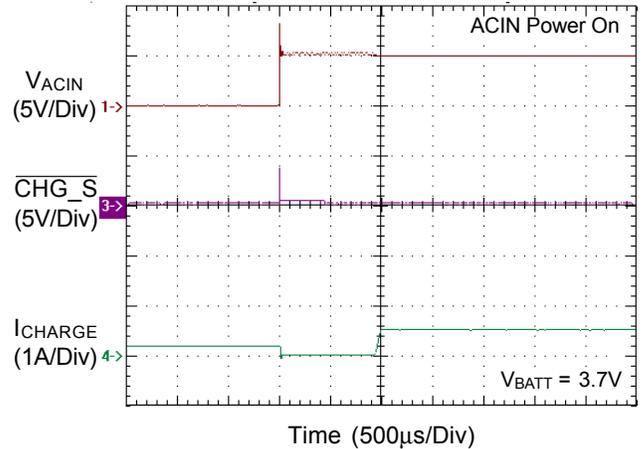
ACIN OVP



Input Voltage Transition



Input Voltage Transition



Application Information

Automatically Power Source Selection

The HM80133 is a battery charger IC which is designed for Li-ion Battery with 4.2V rated voltage.

AC Mode : When the AC input voltage (ACIN) is higher than the UVP voltage level (4.4V), the HM8013 will enter AC Mode. In the AC Mode, ACIN P-MOSFET is turned on and USB P-MOSFET is turned off.

Sleep Mode : The HM8013 will enter Sleep Mode when AC input voltage are removed. This feature provides low leakage current from the battery during the absence of input supply.

ACIN Over Voltage Protection

The AC input voltage is monitored by an internal OVP comparator. The comparator has an accurate reference of 2.5V from the band-gap reference. The OVP threshold is set by the internal resistive. The protection threshold is set to 6.5V. When the input voltage exceeds the threshold, the comparator outputs a logic signal to turn off the power P-MOSFET to prevent the high input voltage from damaging the electronics in the handheld system. When the input over voltage condition is removed (ACIN < 6V), the comparator re-enables the output by running through the soft-start.

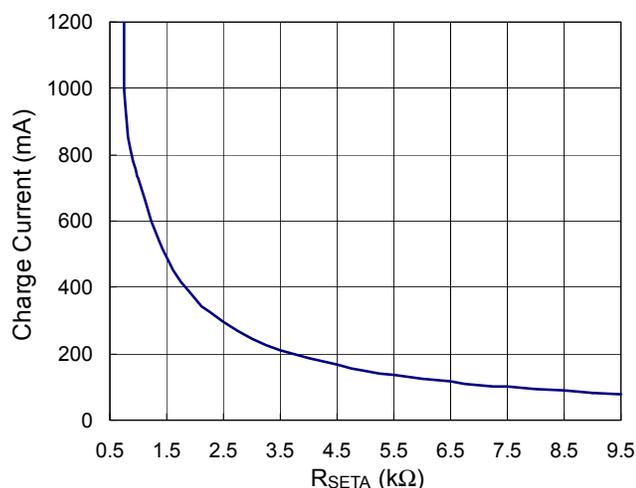


Figure 1. AC Mode Charge Current Setting

Fast-Charge Current Setting

The HM8013 offers ISETA pin to determine the AC charge rate from 100mA to 1.2A. The charge current can be calculated as following equation.

$$I_{\text{charge_ac}} = K_{\text{SET}} \frac{V_{\text{SET}}}{R_{\text{SETA}}}$$

The parameter $K_{\text{SET}} = 300$; $V_{\text{SET}} = 2.5\text{V}$. R_{SETA} is the resistor connected between the ISETA and GND.

Pre- Charge Current Setting

During a charge cycle if the battery voltage is below the VPRech threshold, the HM8013 applies a pre-charge mode to the battery. This feature revives deeply discharged cells and protects battery life. The HM8013 internal determines the pre-charge rate as 10% of the fast-charge current.

Battery Voltage Regulation

The HM8013 monitors the battery voltage through the BAT pin. Once the battery voltage level closes to the VREG threshold, the HM8013 voltage enters constant phase and the charging current begins to taper down. When battery voltage is over the VREG threshold, the HM8013 will stop charge and keep to monitor the battery voltage. However when the battery voltage decreases 100mV below the VREG, it will be recharged to keep the battery voltage.

Charge Status Outputs

The open-drain $\overline{\text{CHG_S}}$ and $\overline{\text{PGOOD}}$ outputs indicate various charger operations as shown in the following table.

These status pins can be used to drive LEDs or communicate to the host processor. Note that ON indicates the open-drain transistor is turned on and LED is bright.

Charge State		$\overline{\text{CHG_S}}$	$\overline{\text{PGOOD}}$
ACIN	Charge	ON	ON
	Charge done	OFF	ON

Temperature Regulation and Thermal Protection

In order to maximize the charge rate, the HM8013 features a junction temperature regulation loop. If the power dissipation of the IC results in a junction temperature greater than the thermal regulation threshold (125°C), the HM8013 throttles back on the charge current in order to maintain a junction temperature around the thermal regulation threshold (125). The HM8013 monitors the junction temperature, T_J , of the die and disconnects the battery from the input if T_J exceeds 125°C. This operation continues until junction temperature falls below thermal regulation threshold (125 °C) by the hysteresis level. This feature prevents the chip from damage.

Selecting the Input and Output Capacitors

In most applications, the most important is the high-frequency decoupling capacitor on the input of the HM8013. A 1uF ceramic capacitor, placed in close proximity to input pin and GND pin is recommended. In some applications depending on the power supply characteristics and cable length, it may be necessary to add an additional 10uF ceramic capacitor to the input. The HM8013 requires a small output capacitor for loop stability. A 1uF ceramic capacitor placed between the BATT pin and GND is typically sufficient.

Layout Consideration

The HM8013 is a fully integrated low cost single-cell Li-Ion battery charger ideal for portable applications. Careful PCB layout is necessary. For best performance, place all peripheral components as close to the IC as possible. A short connection is highly recommended. The following guidelines should be strictly followed when designing a PCB layout for the HM8013.

- ▶ Input capacitor should be placed close to IC and connected to ground plane. The trace of input in the PCB should be placed far away the sensitive devices or shielded by the ground.
- ▶ The GND should be connected to a strong ground plane for heat sinking and noise protection.
- ▶ The connection of R_{SETA} should be isolated from other noisy traces. The short wire is recommended to prevent EMI and noise coupling.
- ▶ Output capacitor should be placed close to IC and connected to ground plane to reduce noise coupling.

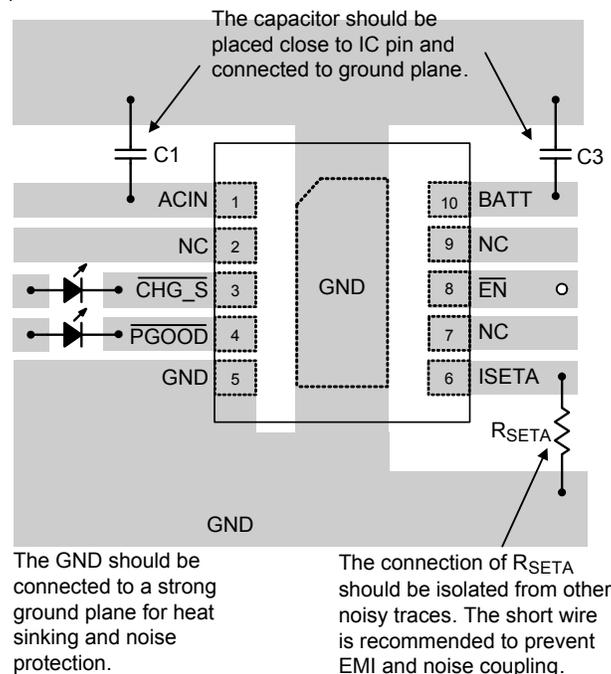
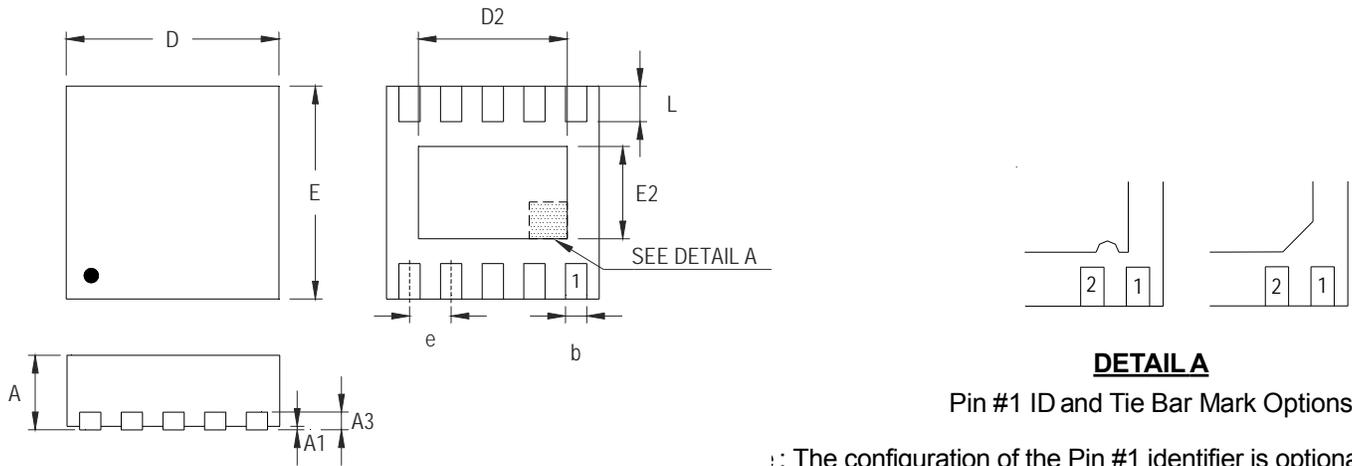


Figure 2

Outline Dimension



DETAIL A

Pin #1 ID and Tie Bar Mark Options

: The configuration of the Pin #1 identifier is optional, but must be located within the zone indicated.

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A3	0.175	0.250	0.007	0.010
b	0.180	0.300	0.007	0.012
D	2.950	3.050	0.116	0.120
D2	2.300	2.650	0.091	0.104
E	2.950	3.050	0.116	0.120
E2	1.500	1.750	0.059	0.069
e	0.500		0.020	
L	0.350	0.450	0.014	0.018

W-Type 10L DFN 3x3 Package